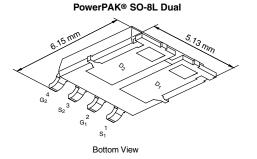


# Automotive Dual P-Channel 30 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V <sub>DS</sub> (V)	- 30
$R_{DS(on)}(\Omega)$ at $V_{GS}$ = - 10 V	0.024
$R_{DS(on)}(\Omega)$ at $V_{GS}$ = - 4.5 V	0.039
I <sub>D</sub> (A) per leg	- 8
Configuration	Dual

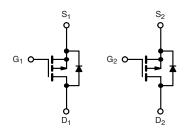


#### FEATURES

- TrenchFET<sup>®</sup> Power MOSFET
- 100 % R<sub>g</sub> and UIS Tested
- AEC-Q101 Qualified<sup>d</sup>
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>



RoHS COMPLIANT HALOGEN FREE



P-Channel MOSFET P-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and Halogen-free	SQJ941EP-T1-GE3

ABSOLUTE MAXIMUM RATING	<b>S</b> (T <sub>C</sub> = 25 °C, unless	otherwise noted	l)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V <sub>DS</sub>	- 30	V	
Gate-Source Voltage		V <sub>GS</sub>	± 20		
Continuous Drain Current <sup>a</sup>	T <sub>C</sub> = 25 °C	1	- 8		
Continuous Drain Current"	T <sub>C</sub> = 125 °C	I <sub>D</sub>	- 8		
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	- 8	А	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	- 32		
Single Pulse Avalanche Current		I <sub>AS</sub>	- 24		
Single Pulse Avalanche Energy		E <sub>AS</sub>	28.8	mJ	
Maximum Power Dissipation <sup>b</sup>	T <sub>C</sub> = 25 °C	D	55	W	
Maximum Power Dissipation	T <sub>C</sub> = 125 °C	P <sub>D</sub>	18.5	vv	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to + 175	*	
Soldering Recommendations (Peak Temperature) <sup>e, f</sup>			260	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient PC	CB Mount <sup>c</sup>	R <sub>thJA</sub>	85	°C/W
Junction-to-Case (Drain)		R <sub>thJC</sub>	2.7	0/10

#### Notes

- a. Package limited.
- b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.
- e. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SO-8L. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- f. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

S12-1848-Rev. C, 30-Jul-12

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SQ,	J941	EP

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	V <sub>GS</sub> :	= 0, I <sub>D</sub> = - 250 μA	- 30	-	-	v
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$		- 2.0	- 2.5	v
Gate-Source Leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	0 V, $V_{GS}$ = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = - 30 V	-	-	- 1	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 V$	$V_{DS} = -30 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	- 50	μA
		$V_{GS} = 0 V$	$V_{DS} = -30 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	- 150	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = - 10 V	V <sub>DS</sub> = - 5 V	- 24	-	-	Α
		V <sub>GS</sub> = - 10 V	I <sub>D</sub> = - 9 A	-	0.020	0.024	
Drain Course On State Desistence?		V <sub>GS</sub> = - 10 V	I <sub>D</sub> = - 9 A, T <sub>J</sub> = 125 °C	-	0.028	0.034	Ω
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 10 V	I <sub>D</sub> = - 9 A, T <sub>J</sub> = 175 °C	-	0.032	0.039	
		$V_{GS} = -4.5 V$	I <sub>D</sub> = - 5 A	-	0.032	0.039	
Forward Transconductanceb	g <sub>fs</sub>	V <sub>DS</sub> =	- 15 V, I <sub>D</sub> = - 2.5 A	-	10	-	S
Dynamic <sup>b</sup>		-					
Input Capacitance	C <sub>iss</sub>			-	1500	1800	
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = - 10 V, f = 1 MHz	-	370	445	pF
Reverse Transfer Capacitance	C <sub>rss</sub>			-	260	315	1
Total Gate Charge <sup>c</sup>	Qg			-	35	55	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>GS</sub> = - 10 V	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -9 \text{ A}$	-	4.6	-	nC
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			-	8.1	-	1
Gate Resistance	Rg		f = 1 MHz	2.8	5.95	9.5	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			-	49	60	
Rise Time <sup>c</sup>	t <sub>r</sub>		- 15 V, R <sub>I</sub> = 1.66 Ω	-	35	50	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	I <sub>D</sub> ≅ - 9 A, \	$V_{\text{GEN}} = -10 \text{ V}, \text{ R}_{\text{g}} = 6 \Omega$	-	47	60	ns
Fall Time <sup>c</sup>	t <sub>f</sub>	1		-	26	33	
Source-Drain Diode Ratings and Char	acteristics <sup>b</sup>	•					
Pulsed Current <sup>a</sup>	I <sub>SM</sub>			-	-	- 32	А
i uiseu Ourrent	'SIVI						

Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

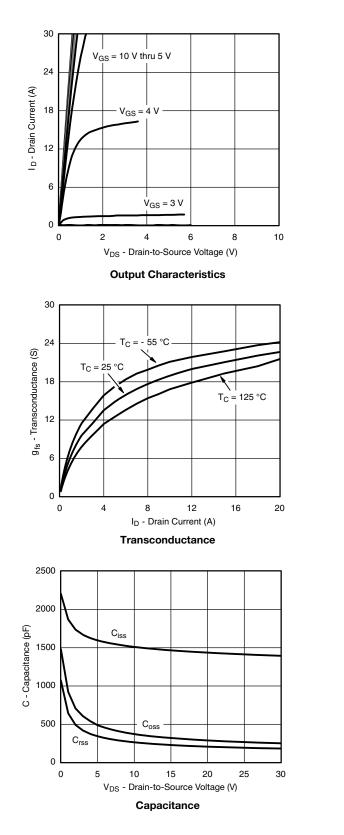
c. Independent of operating temperature.

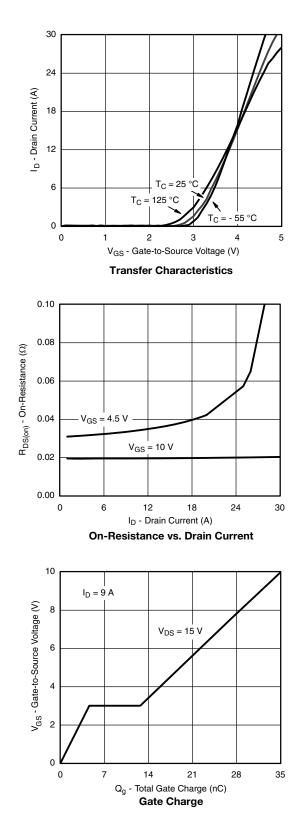
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



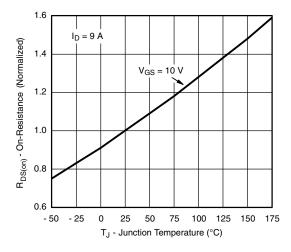


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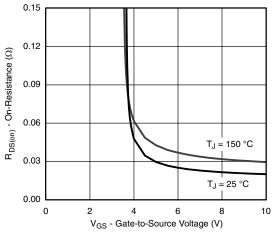
SQJ941EP

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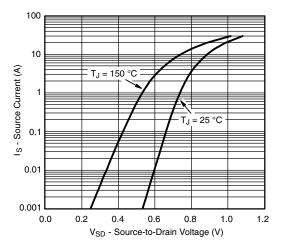
### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



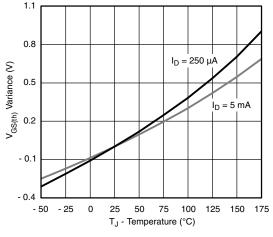
**On-Resistance vs. Junction Temperature** 



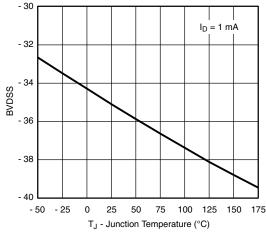
**On-Resistance vs. Gate-to-Source Voltage** 



Source Drain Diode Forward Voltage





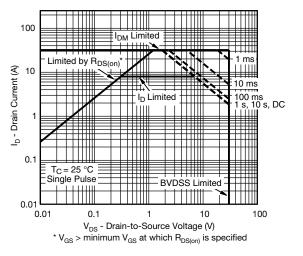


**BVDSS vs. Junction Temperature** 

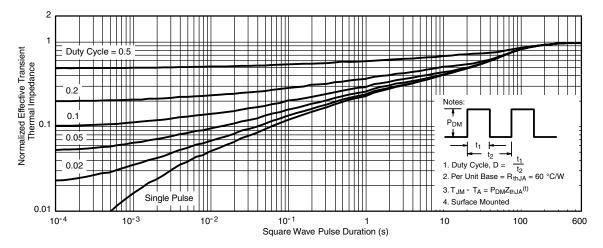
4



### **THERMAL RATINGS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



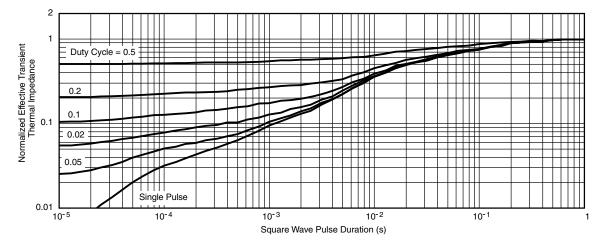
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



#### **THERMAL RATINGS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

#### Note

The characteristics shown in the two graphs

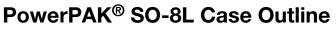
- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

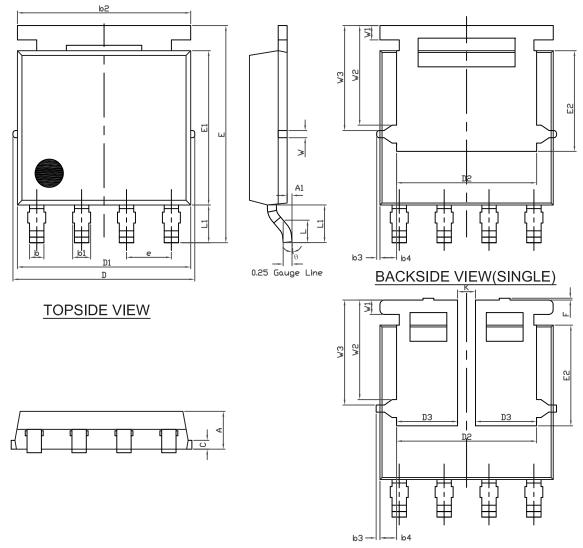
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?65546">www.vishay.com/ppg?65546</a>.







BACKSIDE VIEW(DUAL)

### **Package Information**



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DIM.	MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094	·		0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC	·	0.050 BSC			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2 (for AI product)	2.75	2.85	2.95	0.108	0.112	0.116	
E2 (for other product)	3.18	3.28	3.38	0.125	0.129	0.133	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
К		0.51		0.020			
W	0.23		0.009				
W1	0.41		0.016				
W2	2.82		0.111				
W3		2.96		0.117			
θ	0°	-	10°	0°	-	10°	

Note

• Millimeters will gover



#### **RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L DUAL**



Recommended Minimum Pads Dimensions in mm (inches) Keep-out 6.75 (0.266) x 7.75 (0.305)

Revision: 07-Feb-12



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